

General Purpose Transistors

NPN Silicon

MAXIMUM RATINGS

Rating	Symbol	BC846	BC847	BC848	Unit
Collector-Emitter Voltage	V_{CEO}	65	45	30	V
Collector-Base Voltage	V_{CBO}	80	50	30	V
Emitter-Base Voltage	V_{EBO}	6.0	6.0	5.0	V
Collector Current — Continuous	I_C	100	100	100	mAdc
Collector Current(Peak value)	I_{CM}	200	200	200	mAdc
Emitter Current(Peak value)	I_{EM}	200	200	200	mAdc
Base Current(Peak value)	I_{BM}	200	200	200	mAdc

SOLDERING CHARACTERISTICS

Characteristic	Symbol	Unit
Solder Heat Resistance	265	°C
Solderability	240 to 265	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR- 5 Board, (1)	P_D		
$T_A = 25^\circ\text{C}$		225	mW
Derate above 25°C		1.8	$\text{mW}/^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	$^\circ\text{C}/\text{W}$
Total Device Dissipation	P_D		
Alumina Substrate, (2) $T_A = 25^\circ\text{C}$		300	mW
Derate above 25°C		2.4	$\text{mW}/^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature	T_J, T_{stg}	-55 to +150	°C

DEVICE MARKING

BC846ALT1 = 1A; BC846BLT1 = 1B; BC847ALT1 = 1E; BC847BLT1 = 1F;
 BC847CLT1 = 1G; BC848ALT1 = 1J; BC848BLT1 = 1K; BC848CLT1 = 1L

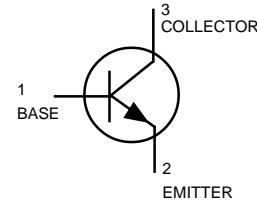
ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector-Emitter Breakdown Voltage ($I_C = 10 \text{ mA}$)	$V_{(BR)CEO}$	65	—	—	v
		45	—	—	
		30	—	—	
Collector-Emitter Breakdown Voltage ($I_C = 10 \mu\text{A}, V_{EB} = 0$)	$V_{(BR)CES}$	80	—	—	v
		50	—	—	
		30	—	—	
Collector-Base Breakdown Voltage ($I_C = 10 \mu\text{A}$)	$V_{(BR)CBO}$	80	—	—	v
		50	—	—	
		30	—	—	
Emitter-Base Breakdown Voltage ($I_E = 1.0 \mu\text{A}$)	$V_{(BR)EBO}$	6.0	—	—	
		5.0	—	—	
		5.0	—	—	
Collector Cutoff Current ($V_{CB} = 30 \text{ V}$)	I_{CBO}	—	—	15	nA
($V_{CB} = 30 \text{ V}, T_A = 150^\circ\text{C}$)		—	—	5.0	μA

1. FR-5 = $1.0 \times 0.75 \times 0.062$ in

2. Alumina = $0.4 \times 0.3 \times 0.024$ in. 99.5% alumina.

BC846ALT1,BLT1
BC847ALT1,BLT1
CLT1 thru
BC850BLT1,CLT1



BC846ALT1,BLT1 BC847ALT1,BLT1 CLT1 thru BC850BLT1,CLT1

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Typ	Max	Unit
ON CHARACTERISTICS					
DC Current Gain ($I_C = 10 \mu\text{A}$, $V_{CE} = 5.0 \text{ V}$)	h_{FE}	—	90	—	—
BC846B, BC847B, BC848B		—	150	—	
BC847C, BC848C		—	270	—	
($I_C = 2.0 \text{ mA}$, $V_{CE} = 5.0 \text{ V}$)	BC846A, BC847A, BC848A	110	180	220	
BC846B, BC847B, BC848B, BC849B, BC850B		200	290	450	
BC847C, BC848C, BC849C, BC850C		420	520	800	
Collector-Emitter Saturation Voltage ($I_C = 10 \text{ mA}$, $I_B = 0.5 \text{ mA}$) ($I_C = 100 \text{ mA}$, $I_B = 5.0 \text{ mA}$)	$V_{CE(sat)}$	—	—	0.25	V
—		—	—	0.6	
Base-Emitter Saturation Voltage ($I_C = 10 \text{ mA}$, $I_B = 0.5 \text{ mA}$) ($I_C = 100 \text{ mA}$, $I_B = 5.0 \text{ mA}$)	$V_{BE(sat)}$	—	0.7	—	V
—		—	0.9	—	
Base-Emitter Voltage ($I_C = 2.0 \text{ mA}$, $V_{CE} = 5.0 \text{ V}$) ($I_C = 10 \text{ mA}$, $V_{CE} = 5.0 \text{ V}$)	$V_{BE(on)}$	580	660	700	mV
—		—	—	770	

SMALL-SIGNAL CHARACTERISTICS

Current-Gain — Bandwidth Product ($I_C = 10 \text{ mA}$, $V_{CE} = 5.0 \text{ Vdc}$, $f = 100 \text{ MHz}$)	f_T	100	—	—	MHz
Output Capacitance ($V_{CB} = 10 \text{ V}$, $f = 1.0 \text{ MHz}$)	C_{obo}	—	—	4.5	pF
Noise Figure ($I_C = 0.2 \text{ mA}$, BC846A, BC847A, BC848A $V_{CE} = 5.0 \text{ Vdc}$, $R_S = 2.0 \text{ k}\Omega$, BC846B, BC847B, BC848B $f = 1.0 \text{ kHz}$, BW = 200 Hz) BC847C, BC848C BC849B,C, BC850B,C	NF	—	—	10	dB
		—	—	4.0	

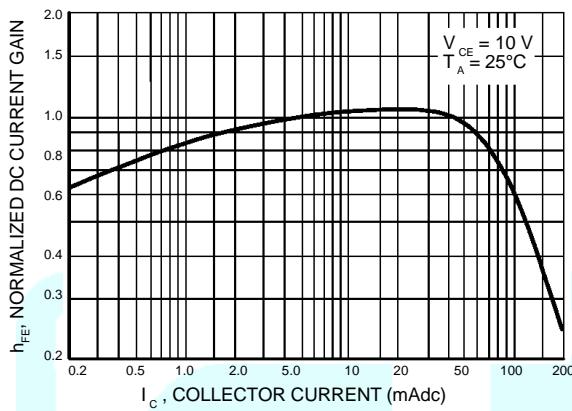


Figure 1. Normalized DC Current Gain

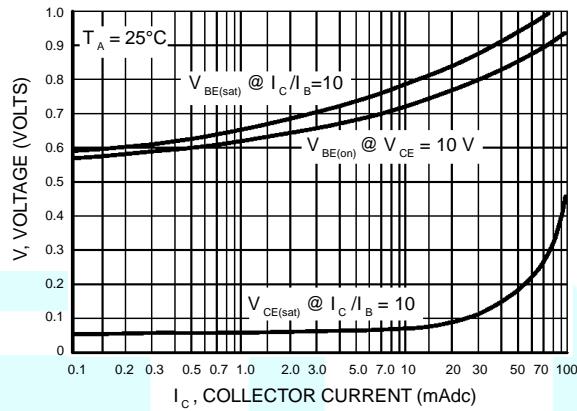


Figure 2. "Saturation" and "On" Voltages

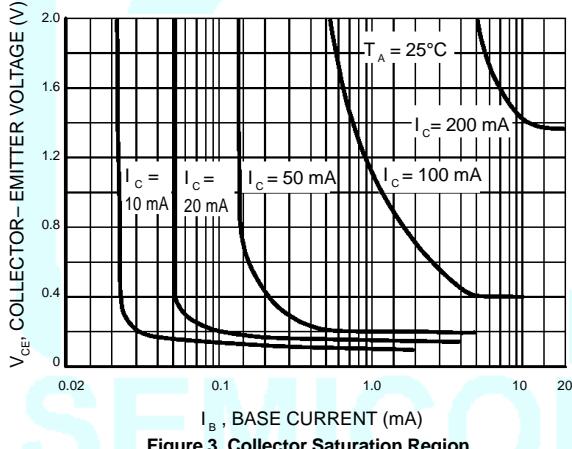


Figure 3. Collector Saturation Region

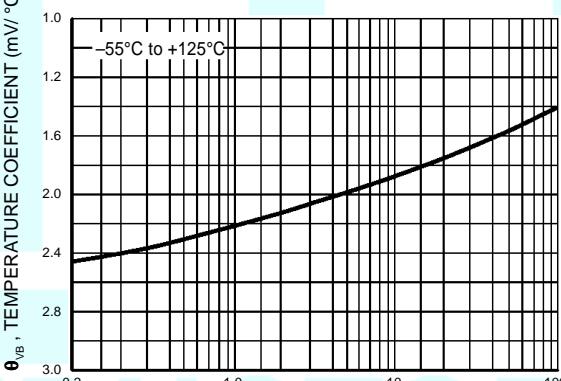


Figure 4. Base-Emitter Temperature Coefficient

BC846ALT1,BLT1 BC847ALT1,BLT1 CLT1 thru BC850BLT1,CLT1

BC847/BC848

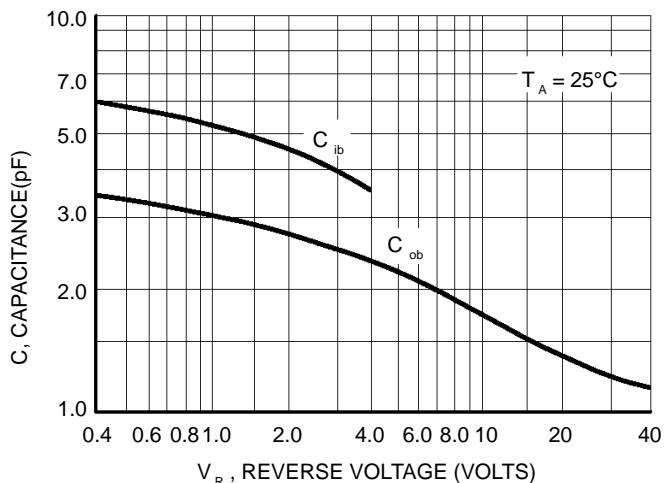


Figure 5. Capacitances

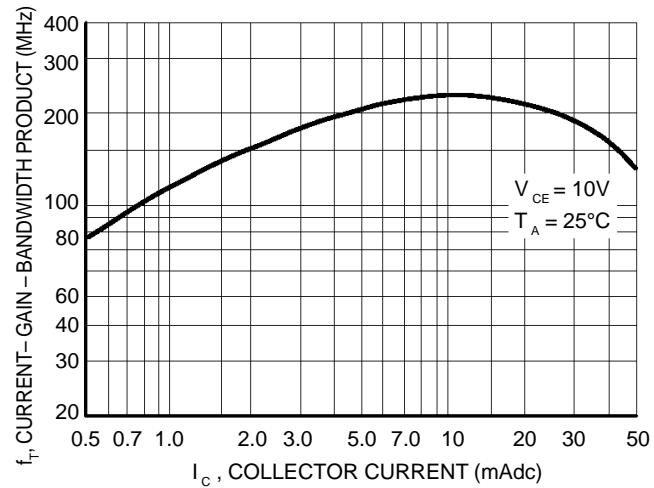


Figure 6. Current-Gain – Bandwidth Product

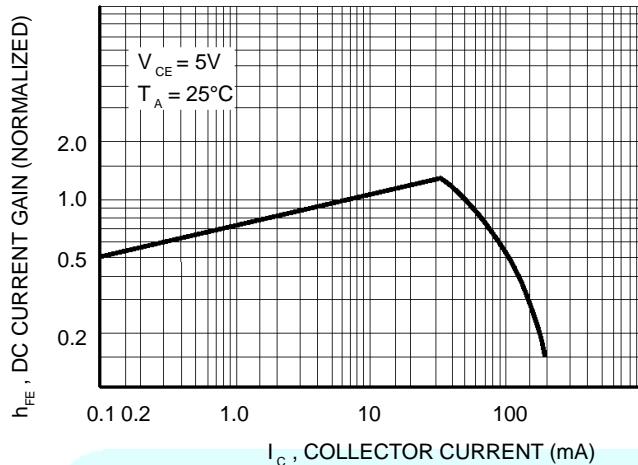


Figure 7. DC Current Gain

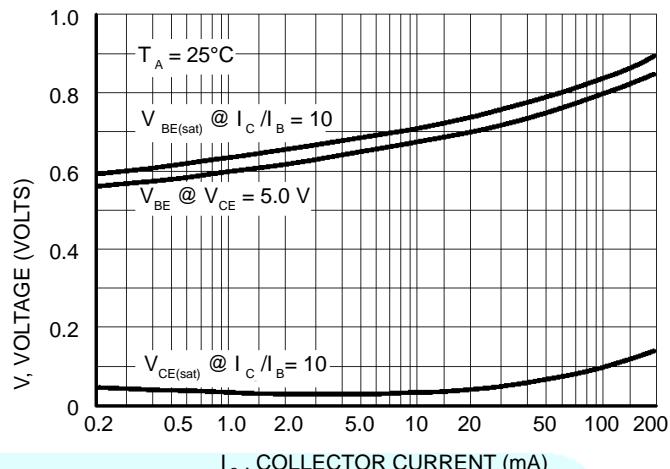


Figure 8. "On" Voltage

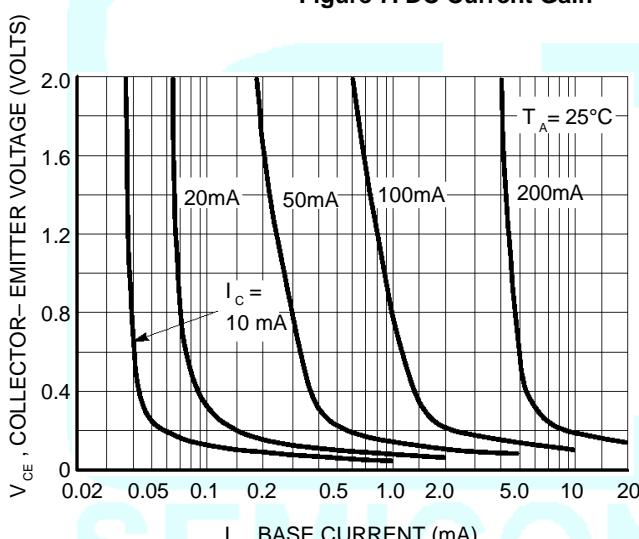


Figure 9. Collector Saturation Region

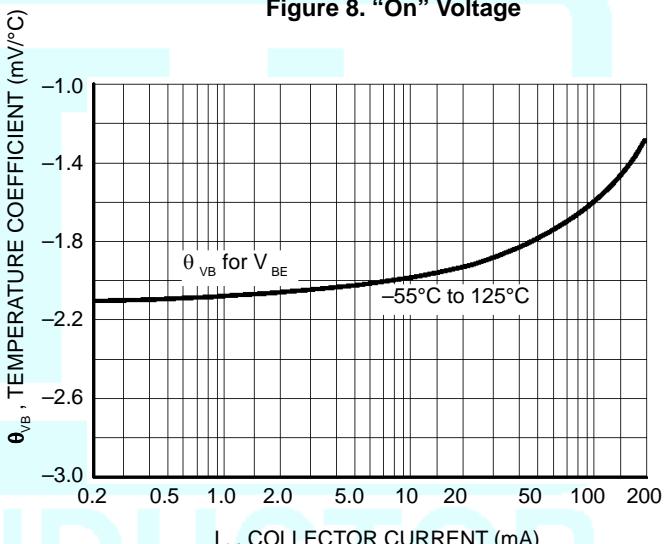


Figure 10. Base–Emitter Temperature Coefficient

BC846ALT1, BLT1 BC847ALT1, BLT1 CLT1 thru BC850BLT1, CLT1
BC846
